	Application No.	Applicant(s)
Notice of Allowability	10/665,422	KOBAYASHI ET AL.
	Examiner	Art Unit
	H.Jey Tsai	2812
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.		
1. This communication is responsive to <u>paper filed on 9/28/04</u> .		
2. The allowed claim(s) is/are <u>1-5</u> .		
3. The drawings filed on 22 September 2003 are accepted by the Examiner.		
4.		
 Attachment(s) 1. ☑ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 11/24/04 4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material 	6. ☐ Interview Summary Paper No./Mail Dat 8), 7. ☑ Examiner's Amenda	e

Examiner Amendment And Reasons For Allowance

Examiner Amendment

An Examiner's Amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 C.F.R. § 1.312. To ensure consideration of such an amendment, it **MUST** be submitted no later than the payment of the Issue Fee.

This application is in condition for allowance except for the presence of nonelected claims 6-8. Accordingly, claims 6-8 are canceled.

The application has been amended as follows:

In the claims:

1. (Currently Amended) A method for manufacturing a piezoelectric element comprising:

a coating step of coating a substrate with a coating liquid for forming the piezoelectric element thereby forming a coated film, film;

a drying step of drying said coated film, film;

a preliminary sintering step of preliminarily sintering said coated film thereby forming an oxide film, film;

a final sintering step of finally sintering said oxide film thereby forming a piezoelectric film, film; and

a cooling step of cooling said piezoelectric film; film,

wherein said steps are coating step is executed in the presence of a moisture-containing gas; in said coating step said substrate has a temperature equal to or less than 50°C and the moisture-containing gas has having a relative humidity of 60

Application/Control Number: 10/665,422

Art Unit: 2812

%RH or less at 25°C; <u>25°C, and, in said coating step, said substrate has a temperature</u> equal to or less than <u>50°C</u>,

wherein said drying step is executed in the presence of a moisturecontaining gas having a relative humidity of 10 to 70 %RH at 25°C, and, in said drying step, said substrate has a temperature equal to or less than 200°C, and said relative humidity is 10 to 70 %RH;

wherein said preliminary sintering step is executed in the presence of a moisture-containing gas having a relative humidity of 70 to 100 %RH at 25°C, and, in said preliminary sintering step, said substrate has a temperature of 200 to 450°C, and said relative humidity is 70 to 100 %RH;

wherein said final sintering step is executed in the presence of a moisture-containing gas having a relative humidity of 70 to 100 %RH at 25°C, and, in said final sintering step, said substrate has a temperature of 500 to 800°C and said relative humidity is 70 to 100 %RH.

2. (Currently Amended) A method for manufacturing a piezoelectric film element according to claim 1, wherein the moisture-containing gas present in said preliminary sintering step, the moisture-containing gas present in said final sintering step, and the moisture-containing gas present in said cooling step each contains oxygen by 10 vol% or more.

Application/Control Number: 10/665,422 Page 4

Art Unit: 2812

3. (Currently Amended) A method for manufacturing a piezoelectric film element according to claim 1, wherein said coating liquid includes a raw material component of the said piezoelectric film, with said piezoelectric film containing at least one of Pb, La, Zr, and Ti as a constituent element.

- 4. (Currently Amended) A method for manufacturing a piezoelectric film element according to claim 1, wherein said coating liquid includes a raw material component of the said piezoelectric film obtained by reacting (a) a metal alkoxide or a metal salt and (b) water in a solvent having a boiling point equal to or higher than 100°C or in a solvent containing such solvent.
- 5. (Currently Amended) A method for manufacturing a piezoelectric film element according to claim 1, wherein in the said cooling step, the is executed in the presence of a moisture-containing gas having a relative humidity is of 70 to 100 %RH at 25°C.

6 to 8. (Cancelled)

Authorization for this Examiner's Amendment was given in a telephone interview and electronic communication with Mr. D. Vadnais on Nov. 29, 2004.

Reasons For Allowance

Application/Control Number: 10/665,422

Art Unit: 2812

The following is an Examiner's statement of reasons for the indication of allowable subject matter:

The basis for the allowability is:

Prior art record does not teaches coating step is executed in the presence of a moisture-containing gas having a relative humidity of 60 %RH or less at 25°C, and, in the coating step, the substrate has a temperature equal to or less than 50°C, drying step is executed in the presence of a moisture-containing gas having a relative humidity of 10 to 70 %RH at 25°C, in the drying step, the substrate has a temperature equal to or less than 200°C, the preliminary sintering step is executed in the presence of a moisture-containing gas having a relative humidity of 70 to 100 %RH at 25°C, in the preliminary sintering step, the substrate has a temperature of 200 to 450°C, the final sintering step is executed in the presence of a moisture-containing gas having a relative humidity of 70 to 100 %RH at 25°C, and, in the final sintering step, said substrate has a temperature of 500 to 800°C.

Applicant is reminded that upon the cancellation of claims to a non-elected invention, the inventorship must be amended in compliance with 37 C.F.R. § 1.48(b) if one or more of the currently named inventors is no longer an inventor of at least one claim remaining in the application. Any amendment of inventorship must be accompanied by a diligently-filed petition under 37 C.F.R. § 1.48(b) and by the fee required under 37 C.F.R. § 1.17(h).

Any comments considered necessary by applicant must be submitted no later than the payment of the Issue Fee and, to avoid processing delays, should preferably **accompany** the Issue Fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance".

Any inquiry of a general nature or clerical matters or relating to the status of this application or proceeding should be directed to the customer service whose telephone number is (703) 308-4357.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to H. Jey Tsai whose telephone number is (571) 272-1684. The examiner can normally be reached on from 7:00 Am to 4:00 Pm., Monday thru Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling can be reached on (571) 272-1679.

The fax phone number for this Group is (703) 872-9306.

Art Unit: 2812

hjt

11/29/04

H. Jey Tsai Primary Examiner Patent Examining Group 2800